

UNPARALLELED COMMITMENT & SOLUTIONS

Act like someone's life depends on what we do.







U.S. ARMY ARMAMENT RESEARCH, DEVELOPMENT & ENGINEERING CENTER

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OUTLINE



- MEMS G-Switch Background
- Requirement Establishment
- Standards
- Design Concept
- Encapsulation Process & Highlights
- Technical Challenges and Solutions
- Qualification Tests
- Live Fire Test
- Summary





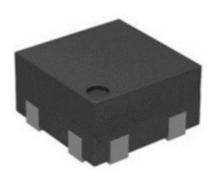
BACKGROUND



- U.S. Army PM-MAS Planned Application
 - M433 low velocity M550 fuze improvement program incorporates an electronic interface to the M550 mechanical fuze.



- Current MEMS G-Switch (HT Micro Inc. production) demonstrated improvements on 40mm low velocity grenade
 - Soft target performance
 - Graze angle impact performance
- Commercial Encapsulation Process (Promex Inc. provided) Needed to:
 - Withstand environmental extremes
 - Provide better resistance to shear force loads
 - Provide a standard package amenable 'pick and place'





REQUIREMENT ESTABLISHING



1. Physical Requirements:

- ✓ Size: Maximum dimension (L x W x H): 4 x 4 x 1.75 in milimeter
- ✓ Package frame type: Quad Flat No-lead (QFN) or Dual Flat No-Lead (DFN) package with 4 to 12 leads
- ✓ Serial number and model name with laser mark
- ✓ Electronics protection: wire bonding, electronics contacts
- ✓ Packaging color: Black with gold or white lead pads
- ✓ Vendor's process specification: encapsulant, wire bonding and die attaching material and physical dimensions

2. Operation/ Transportation Environment Requirements

- ✓ Mechanical shock, impact and vibration
- ✓ Thermal shock, temperature cycling and humidity environment

3. High reliability required

- Maintain MEMS device functionality and provide physical protection.
 - No voids or warpage
 - Resist corrosion and contact discontinuity
- ✓ Meet storage temperature from -65°F to +165°F (-54°C to + 74°C) and shelf life of 20 years.





STANDARDS



- MIL-STD-883J, 'Test Method Standard for Microcircuits'
- MIL-STD-331C, 'Fuze and Fuze Components Environmental and Performance Tests'
- MIL-STD-810G, 'Test Method STD-Environmental Engineering Considerations and Lab Tests'
- MIL-STD-1316E, 'Fuze Design Safety Criteria'
- JEDEC No 22-A110B 'Highly Accelerated Temperature and Humidity Stress Test (HAST)
- MIL-HDBK-338, Electronic Reliability Design Handbook





DESIGN CONCEPT



Commercial standard
 4 X 4 - 12 lead Dual Flat No-Lead (DFN) package

Bare MEMS Encapsulated MEMS Final Product Standard Mold Compound (Encapsulant) MININ **Contact Pads** Wirebonding doubled on each pad



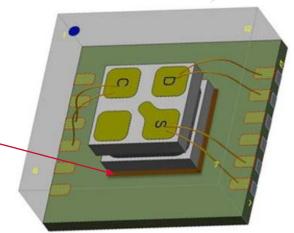


RDECOM ENCAPSULATION HIGHLIGHT 1



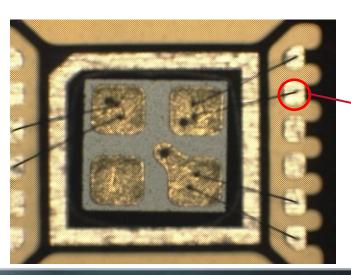
1. Die attaching

- ✓ MEMS G-switch placed and cemented onto the lead frame
- ✓ Electrically insulative epoxy adhesive used



2. Wire bonding

- ✓ Contact pads on G-switch have double gold wires. bonded onto each leaf frame pad for a secure connection.
- ✓ Combination of ball bonding and wedge bonding





* Promex Inc. provided





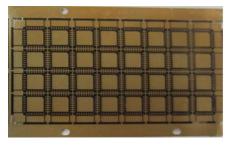
ENCAPSULATION HIGHLIGHT 2

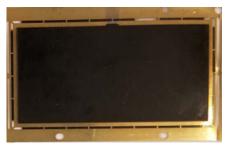


3. Encapsulation

- ✓ Mold Insert placed onto a lead frame for overmolding.
- Mold compound forms a strong overmold

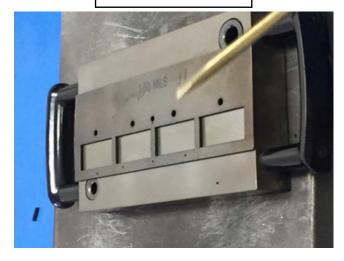


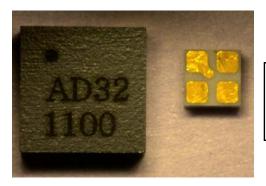




Overmolded Lead Frame

Mold Insert





Encapsulated **Product and Original** G - Switch

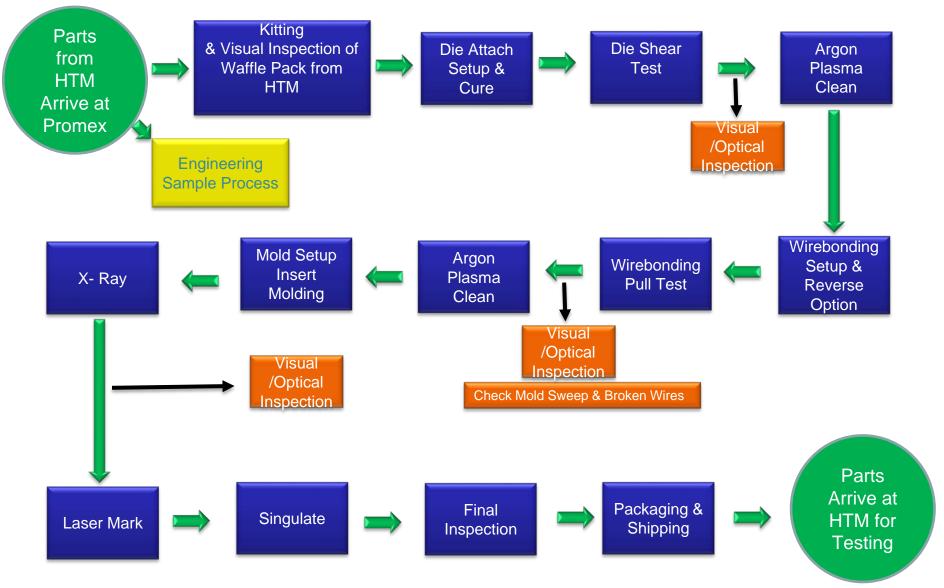
^{*} Promex Inc. provided





ENCAPSULATION PROCESS









TECHNICAL CHALLENGES

Laser Mark & Model Name

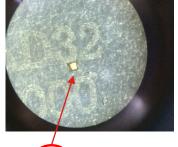


- Voids occurred on top of wire contact area during the molding process in the initial 3 x 3 x 1.5 encapsulation design.
 - Space between wire and top surface was too shallow.
 - Wire bonding was too stiff in vertical angle.
- Problem solving
 - Reverse wire-bonding adopted
 - Mold height increased to 1.75 mm

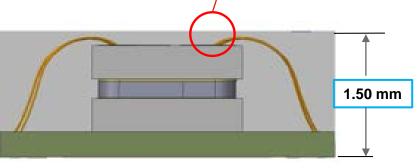
* Top surface image with laser mark & serial number

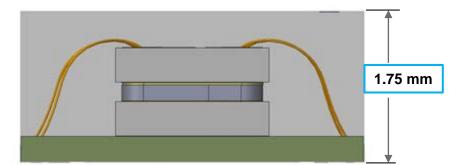


* Void on Wirebonding



No Void





^{*} Promex Inc. provided





QUALIFICATION TESTING



- Environmental testing
 - Centrifuge Functionality Test (before and after encapsulation)
 - Vibration Test
 - Temperature Cycling
 - Thermal Shock
 - Highly Accelerated Stress Test (HAST)
 - All tests followed by centrifuge functionality test
 - * Spin simulation (side orientation)
 - * Impact simulation (down or bottom orientation)
- High G 'shock and impact' testing
 - Air-Gun Test (155 mm Artillery Environment)
 - Shock Arm Test
- Live fire gun testing
 - MK-19 Grenade Launcher (low velocity 40 mm live gun fire)





FUNCTIONALITY TEST



- Centrifuge test for baseline functionality before and after encapsulation to observe any changes
- Pass/Fail criteria
 A device is considered to pass if there is no apparent physical damage or deterioration and the switch still functions with its closures at threshold.
 - Test showed all switches closed within threshold.
 - No differences observed between before and after encapsulation.



Centrifuge spinner setup

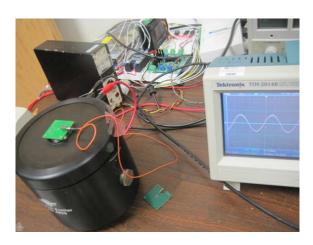




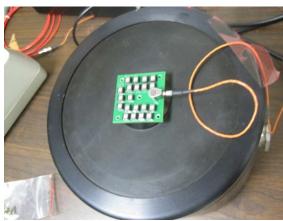
VIBRATION TEST



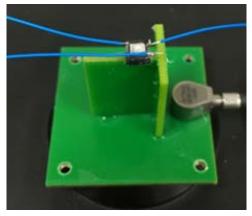
- Purpose
 Component to withstand moderate to severe vibration as a result of motion produced by transportation or field operation.
- Method Vibration, Variable Frequency (MIL-STD-883, Test Method 2007.3)
- Result
 All units showed an expected closure pattern at threshold range without abnormal behavior.



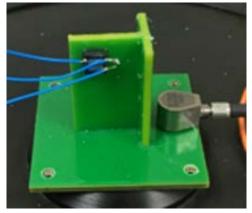
Test setup with vibrator and frequency monitor



Group test setup



Horizontal setup for spin sensing



Vertical setup for impact sensing

^{*} HT Micro Inc. provided





RDECOM® TEMPERATURE CYCLING



Purpose

This test is conducted to determine the resistance of a part to extremes of high and low temperatures, and to the effect of alternate exposures to these extremes.

Method

'Dry' test with temperature condition C as in 'MIL-STD-883J, METHOD 1010.8'

Test Condition

Step	Time (Minutes)	Test Condition Temperature (°C)
1 (Cold)	Transfer Time ≤ 1min. if needed Dwell Time ≥ 10 min.	-65
2 (Hot)	Transfer Time ≤ 1min. if needed Dwell Time ≥ 10 min.	150

10 cycles

Result

Test data appeared to be very similar to the vibration test data and is interpreted as 'non-affected'.





Hot chamber above and cold chamber bottom at HT Micro





THERMAL SHOCK



Purpose

The purpose of this test is to determine the resistance of the part to sudden exposure to extreme changes in temperature and the effect of alternate exposures to these extremes.

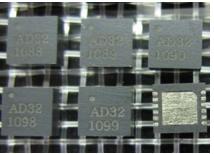
- Method (MIL-STD-883E, METHOD 1011.9)
 - Wet Test with 15 cycles of duration
 - Temperature condition B

Test Condition in MIL-STD-883E

Step	Time	Recommended Fluid	Test Condition Temperature (°C)
1 (Col d)	Transfer Time ≤ 10 sec. 2 min ≤ Dwell Time ≤ 5 min.	Perfluorocarbon	-55
2 (Hot)	Transfer Time ≤ 10 sec 2 min ≤ Dwell Time ≤ 5 min *	Perfluorocarbon	125

Result

Test data showed evenly distributed reactions in data graph indicating that the harsh environment with extreme temperatures and high humidity does not impact the functionality of the switch and the encapsulation work was well processed as well.





MEMS devices soaked in netted container tested at HT Micro





HAST



Do Not Open

Purpose

HAST test was performed for the purpose of evaluating the reliability of near hermetic packaged solid-state devices in humid environments. It employs severe conditions of temperature, humidity, and voltage bias which accelerate the penetration of moisture through the external protective material (encapsulant or seal) or along the interface between the

external protective material and the metallic

conductors which pass through it.

• Test Method & Condition: 'JEDEC Standard JESD22-A110-B' in JEDEC Standard

TITLO D VII GEDELO SVIII WII W				
Test	Condit	Remarks		
Highly Accelerated	130°C/ 85% R.H./	-5V, 0V, +5V bias		
Stress Test (HAST)	2.3 atm./ 96 hrs.			
(JEDEC Standard				
JESD22-A110-B)				



Electric connection wire harness to chamber



Result
 All units that were HAST tested showed no change in characteristics due to that exposure.





HIGH G AIR-GUN TEST



 Survivability Test for encapsulated devices subject to severe impact as a result of suddenly applied forces or abrupt changes in motion.

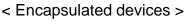
Air-gun Test Configuration

	Acceleration releval. No of Domonto				
Sho	Acceleration g level	No of	Remark		
t	(Air Pressure)	Devices			
	52,221 G		* 5 inch diaphragm air gun		
1		6	* Piston weight: 8.02 oz.		
	(Air pressure: 21,530 psi)		* No. 5 Aluminum shear		
	51,658 G				
2		6	disc (0.56" size)		
	(Air pressure: 21,310 psi)	_			
	52,221 G				
3		6	Total 18 units		
	(Air pressure: 21,530 psi)				



< Air-gun 5 inch diaphragm >

- Test Summary
 - Survived high G environment and functioned at threshold G level.
 - No cracks, warped or damaged surfaces identified.
- Remarks
 - Some differences in G level (average ~40 G) between before and after gun test were found due to multiple severe testing processes in prior tests
 - However they were all above the threshold.







< Test vehicle (bird) >

* Tested at Picatinny





LIVE FIRE GUN TEST

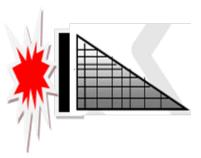


Test Overview

- Low velocity 40mm M433 cartridge live fire test.
- Performed with 'on board recorder' (OBR) capability
- Characterized the encapsulated G-switch's behavior with real gun fire environment.
- Collecting net was used for soft catch simulating snow, tree leaves and sand, etc.

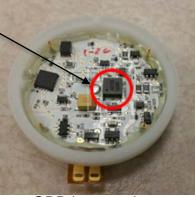


MK-19 Grenade Launcher



Encapsulated G Switch

Target with collecting net



< OBR bottom view >

Test Summary

- OBR data showed closures at expected target levels
- Multiple closures observed as penetrating target and landing in the net.
- 2 data acquisition errors observed but closures already had occurred as expected.



< OBR top view >

^{*} Tested at Picatinny





SUMMARY



- Requirements were established for mechanical design specifying overall encapsulation process.
- A process was developed to provide commercial-grade encapsulation to increase their ruggedness and environmental protection.
- Promex Industries, Inc. was selected to provide the near-hermetic encapsulation technology.
- Technical challenge was resolved by molding height adjustment.
- Required testing was completed and results were tabulated for switch closures in axial and lateral directions, and the before and after switch closure levels were compared.
- Testing showed that the encapsulation process does not negatively affect G-switch function relative to its non-encapsulated state.







Questions?

Thank You!